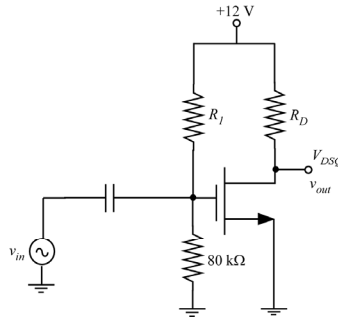


1. For the MOSFET shown,  $V_T = 1\text{ V}$ ,  $\lambda = 0$ , and  $\mu C_{ox} W / 2L = 0.1\text{ mA/V}^2$ . Select  $R_D$  and  $R_I$  to result in a midband voltage gain of  $-4\text{ V/V}$  and  $V_{DSQ} = 7\text{ V}$



2. Design a common-gate stage having a midband voltage gain of  $10\text{ V/V} \pm 10\%$  using a load resistance of  $5\text{ k}\Omega$  and a power supply of  $10\text{ V}$ . The input signal is  $75\text{ mV}$  peak. The device used has  $\mu C_{ox} W / 2L = 3\text{ mA/V}^2$ ,  $g_{mb} = 0.15\text{ } g_m\text{ mA/V}$ ,  $V_T = 1\text{ V}$  and  $\lambda = 0.03/\text{V}$ .

3. The circuit shown is a cascode amplifier. Both devices have values of  $\mu C_{ox} W / 2L = 0.5\text{ mA/V}^2$ ,  $V_T = 0.8\text{ V}$ , and  $\lambda = 0$ . Calculate the voltage gain for the circuit. Ignore the body effect.

